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A Product Line of Diodes Incorporated

ZXTP2012Z

60V PNP LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

Features

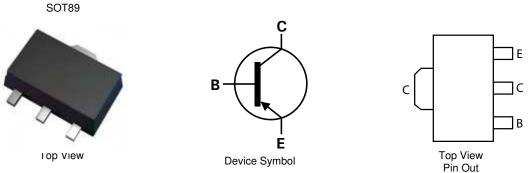
- BV_{CEO} > -60V
- I_C = -4.3A high continuous current
- R_{SAT} = 32mΩ for a low equivalent On-Resistance
- Low saturation voltage V_{CE(sat)} < -65mV @ I_C = -1A
- h_{FE} specified up to -10A for high current gain hold up
- Complementary NPN type: ZXTN2010Z
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.05 grams (Approximate)

Application

- Emergency lighting circuits
- Motor driving (including DC fans)
- Backlight inverters
- Power switches
- Gate driving MOSFETs and IGBTs



Ordering Information (Note 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP2012ZTA	AEC-Q101	951	7	12	1,000
ZXTP2012Z-13R	AEC-Q101	951	13	12	4,000
ZXTP2012ZQTA	Automotive	951	7	12	1,000

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

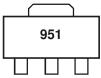
<1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

951 = Product Type Marking Code

5. For packaging details, go to our website at http://www.diodes.com

Marking Information



ZXTP2012Z Datasheet Number: DS33713 Rev. 3 - 2





ZXTP2012Z

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-100	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ι _C	-4.3	A
Peak Pulse Current	I _{CM}	-15	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6) Linear derating factor	PD	1.5 12	W mW/°C
Power Dissipation (Note 7) Linear derating factor	PD	2.1 16.8	W mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	83	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _{0JA}	60	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R _{0JL}	3.23	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	۵°

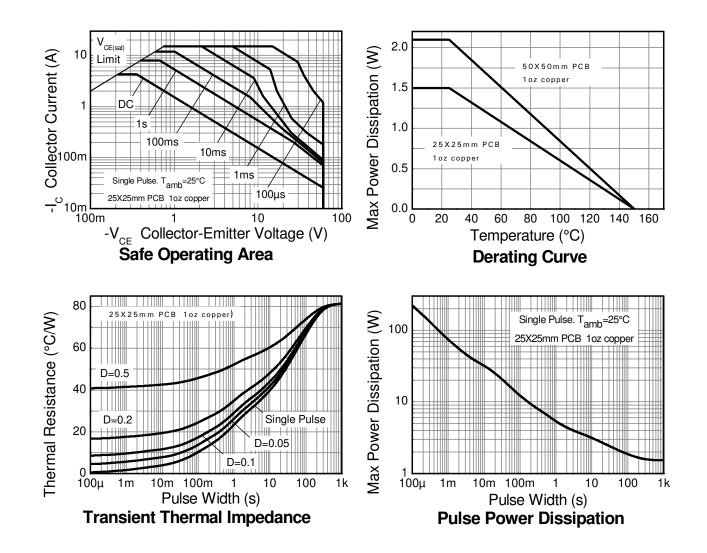
6. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device Notes: measured when operating in steady state condition.

Same as note (6), except the device is mounted on 50mm X 50mm single sided 1oz weight copper.
Thermal resistance from junction to solder-point (on the exposed collector pad).





Thermal Characteristics and Derating Information





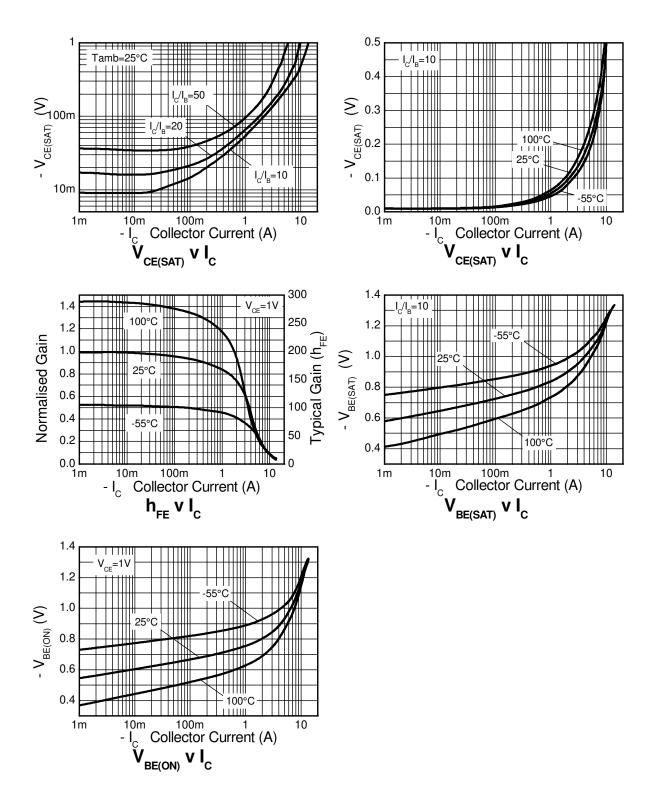


Electrical Characteristics (@T _A = +25°C, unless otherwise specified.)						
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-100	-120	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Notes 9)	BV _{CER}	-100	-120	-	V	$I_{C} = -1\mu A, R_{B} \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Notes 9)	BV _{CEO}	-60	-80	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.1	-	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	-	< -1	-20 -500	nA nA	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Collector Cutoff Current	l _{CER} R≤1kΩ	-	< -1	-20 -500	nA nA	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	-	< -1	-10	nA	$V_{EB} = -6V$
DC current transfer Static ratio (Notes 9)	hFE	100 100 45 10	250 200 90 25	300		
Collector-Emitter Saturation Voltage (Notes 9)	V _{CE(sat)}	-	-14 -50 -75 -160	-20 -65 -110 -215	mV	$\label{eq:lc} \begin{array}{l} I_{C} = -100mA, \ I_{B} = -10mA \\ I_{C} = -1A, \ I_{B} = -100mA \\ I_{C} = -2A, \ I_{B} = -200mA \\ I_{C} = -5A, \ I_{B} = -500mA \end{array}$
Base-Emitter Saturation Voltage (Notes 9)	V _{BE(sat)}	-	-950	-1050	mV	$I_{C} = -5A, I_{B} = -500mA$
Base-Emitter Turn-on Voltage (Notes 9)	V _{BE(on)}	-	-840	-950	mV	$I_{C} = -5A, V_{CE} = -1V$
Transitional Frequency (Notes 9)	f _T	-	120	-	MHz	$I_C = -100mA$, $V_{CE} = -10V$, f = 50MHz
Output capacitance	C _{obo}	-	48	-	pF	$V_{CB} = -10V$, f = 1MHz,
Switching Time	t _{ON} t _{OFF}		39 370	-	ns	$V_{CC} = -10V, I_C = -1A,$ $I_{B1} = I_{B2} = -100mA$

9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%. Notes:



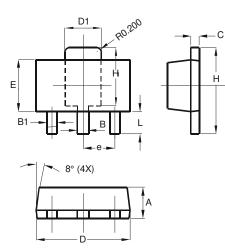
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

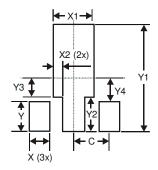
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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